



IRF1310NPBF Information

Part Number IRF1310NPBF

Manufacturer Infineon Technologies

Category

Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description

MOSFET N-CH 100V 42A TO-220AB

TO-220-3 **Package**

For the pricing/inventory/lead time, please contact

Website: https://www.heisener.com

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

For Reference Only

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IRF1310NPBF Specifications

Manufacturer Part Number	IRF1310NPBF
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	HEXFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	100V
Current - Continuous Drain (Id) @ 25°C	42A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	110nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1900pF @ 25V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	160W (Tc)
Rds On (Max) @ Id, Vgs	36 mOhm @ 22A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220AB
Package / Case	TO-220-3
	Report errors?

IRF1310NPBF Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IRF1310NPBF Payment Methods



















IRF1310NPBF Shipping Methods













If you have any question about IRF1310NPBF, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com